1.5KA6.8 thru 1.5KA47A

Vishay General Semiconductor

PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



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PRIMARY CHARACTERISTICS					
V _{WM}	5.5 V to 40.2 V				
V _{BR}	6.8 V to 47 V				
P _{PPM}	1500 W				
PD	6.5 W				
I _{FSM}	200 A				
T _J max.	185 °C				
Polarity	Uni-directional				
Package	1.5KE				

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive and telecommunication.

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- $T_J = 185$ °C capability suitable for high reliability and automotive requirement

Available in uni-directional polarity only

- ROHS COMPLIANT
- 1500 W peak pulse power capability with a 10/1000 μs waveform
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MECHANICAL DATA

Case: Molded epoxy body over passivated junction Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	LIMIT	UNIT				
Peak pulse power dissipation with a 10/1000 μs waveform $^{(1)}$ (fig. 1)	P _{PPM}	1500	W				
Peak pulse current at T_A = 25 °C with a 10/1000 μs waveform $^{(1)}$ (fig. 3)	I _{PPM}	See next table	А				
Power dissipation on infinite heatsink at T_L = 75 °C (fig. 5)	PD	6.5	W				
Peak forward surge current 8.3 ms single half sine-wave (2)	I _{FSM}	200	А				
Maximum instantaneous forward voltage at 100 A (2)	V _F	3.5	V				
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 185	°C				

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2

 $^{(2)}$ 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)									
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} ⁽¹⁾ AT I _T (V)		TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM}	T _J = 150 °C MAXIMUM REVERSE LEAKAGE AT V _{WM}	PEAK PULSE CURRENT I _{PPM} ⁽²⁾	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}	MAXIMUM TEMP. COEFFICIENT OF V _{BR}
	MIN.	MAX.	(117)	(•)	Ι _D (μΑ)	I _D (μΑ)	(A)	V _C (V)	(%/°C)
1.5KA6.8	6.12	7.48	10	5.50	1000	10 000	139	10.8	0.057
1.5KA6.8A	6.45	7.14	10	5.80	1000	10 000	143	10.5	0.057
1.5KA7.5	6.75	8.25	10	6.05	500	5000	128	11.7	0.061
1.5KA7.5A	7.13	7.88	10	6.40	500	5000	133	11.3	0.061
1.5KA8.2	7.38	9.02	10	6.63	200	2000	120	12.5	0.065
1.5KA8.2A	7.79	8.61	10	7.02	200	2000	124	12.1	0.065
1.5KA9.1	8.19	10.0	1.0	7.37	50	500	109	13.8	0.068
1.5KA9.1A	8.65	9.55	1.0	7.78	50	500	112	13.4	0.068
1.5KA10	9.00	11.0	1.0	8.10	20	200	100	15.0	0.073
1.5KA10A	9.50	10.5	1.0	8.55	20	200	103	14.5	0.073
1.5KA11	9.90	12.1	1.0	8.92	5.0	50	92.6	16.2	0.075
1.5KA11A	10.5	11.6	1.0	9.40	5.0	50	96.2	15.6	0.076
1.5KA12	10.8	13.2	1.0	9.72	2.0	10	86.7	17.3	0.076
1.5KA12A	11.4	12.6	1.0	10.2	2.0	10	89.8	16.7	0.078
1.5KA13	11.7	14.3	1.0	10.5	2.0	10	78.9	19.0	0.081
1.5KA13A	12.4	13.7	1.0	11.1	2.0	10	82.4	18.2	0.081
1.5KA15	13.5	16.3	1.0	12.1	1.0	10	68.2	22.0	0.084
1.5KA15A	14.3	15.8	1.0	12.8	1.0	10	70.8	21.2	0.084
1.5KA16	14.4	17.6	1.0	12.9	1.0	10	63.8	23.5	0.086
1.5KA16A	15.2	16.8	1.0	13.6	1.0	10	66.7	22.5	0.086
1.5KA18	16.2	19.8	1.0	14.5	1.0	10	56.6	26.5	0.088
1.5KA18A	17.1	18.9	1.0	15.3	1.0	10	59.5	25.2	0.088
1.5KA20	18.0	22.0	1.0	16.2	1.0	10	51.5	29.1	0.090
1.5KA20A	19.0	21.0	1.0	17.1	1.0	10	54.2	27.7	0.090
1.5KA22	19.8	24.2	1.0	17.8	1.0	10	47.0	31.9	0.092
1.5KA22A	20.9	23.1	1.0	18.8	1.0	10	49.0	30.6	0.092
1.5KA24	21.6	26.4	1.0	19.4	1.0	10	43.2	34.7	0.094
1.5KA24A	22.8	25.2	1.0	20.5	1.0	10	45.2	33.2	0.094
1.5KA27	24.3	29.7	1.0	21.8	1.0	10	38.4	39.1	0.096
1.5KA27A	25.7	28.4	1.0	23.1	1.0	10	40.0	37.5	0.096
1.5KA30	27.0	33.0	1.0	24.3	1.0	10	34.5	43.5	0.097
1.5KA30A	28.5	31.5	1.0	25.6	1.0	10	36.2	41.4	0.097
1.5KA33	29.7	36.3	1.0	26.8	1.0	10	31.4	47.7	0.098
1.5KA33A	31.4	34.7	1.0	28.2	1.0	10	32.8	45.7	0.098
1.5KA36	32.4	39.6	1.0	29.1	1.0	10	28.8	52.0	0.099
1.5KA36A	34.2	37.8	1.0	30.8	1.0	10	30.1	49.9	0.099
1.5KA39	35.1	42.9	1.0	31.6	1.0	10	26.6	56.4	0.100
1.5KA39A	37.1	41.0	1.0	33.3	1.0	10	27.8	53.9	0.100
1.5KA43	38.7	47.3	1.0	34.8	1.0	20	24.2	61.9	0.101
1.5KA43A	40.9	45.2	1.0	36.8	1.0	20	25.3	59.3	0.101
1.5KA47	42.3	51.7	1.0	38.1	1.0	20	22.1	67.8	0.101
1.5KA47A	44.7	49.4	1.0	40.2	1.0	20	23.1	64.8	0.101

Notes

 $^{(1)}$ V_BR measured after I_T applied for 300 μs = square wave pulse or equivalent

 $^{(2)}\,$ Surge current waveform per fig. 3 and derate per fig. 2

⁽³⁾ All terms and symbols are consistent with ANSI/IEEE C62.35

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ORDERING INFORMATION (Example)							
PREFERRED P/N	PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE		BASE QUANTITY	DELIVERY MODE			
1.5KA6.8AHE3/54 (1)	0.916	54	1400	13" diameter paper tape and reel			

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

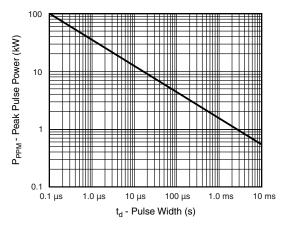


Fig. 1 - Peak Pulse Power Rating Curve

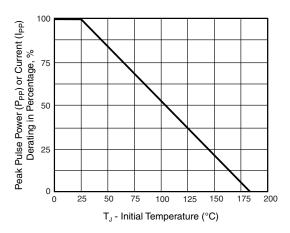


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

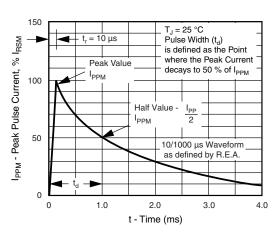


Fig. 3 - Pulse Waveform

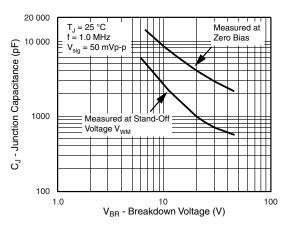


Fig. 4 - Typical Junction Capacitance Unidirectional



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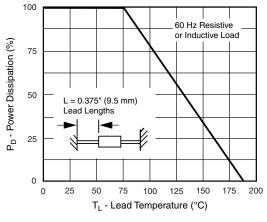


Fig. 5 - Power Derating Curve

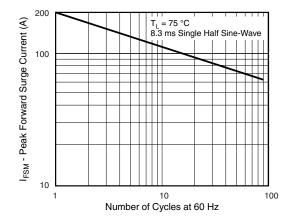
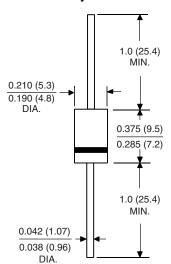


Fig. 6 - Maximum Non-Repetitive/Peak Forward Surge Current







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